# 3A TRCB Load Switch with Auto-discharge

## **General Description**

The ET3159 advanced load management switches target applications requiring a highly integrated solution. It disconnects loads powered from DC Power Rail (<6V) with stringent off-state current targets and high load capacitances (up to 200uF). Each switch consists of slew-rate controlled low-impedance MOSFET Switch and other integrated analog features. The slew-rate controlled turn-on characteristic prevents inrush-current and the resulting excessive voltage droop on power rails.

The ET3159 has True Reverse Current Blocking (TRCB) function blocking unwanted reverse current from OUT to IN during ON/OFF state. These devices have exceptionally low off-state current drain (<1uA max) which facilitate compliance in very low stand-by power applications.. Switch control is managed by a logic input (Active HIGH) capable of interfacing directly with low voltage control signal/GPIO with no external pull-down resistor required,In ET3159, 90 $\Omega$  on-chip load resistor is added for output quick discharge when switch is turned off (EN=0V).

ET3159 is offered DFN4(1.2×1.6) package, which is ideal for small form factor portable equipment .

#### Features

- 1.5V to 6 V Operation voltage range
- Low quiescent current is 8uA typical
- Slew rate/inrush control with t<sub>R</sub> is 0.6ms typical
- Typical R<sub>DS(ON)</sub> is 75mΩ at V<sub>IN</sub>=3.6V
- True reverse current blocking (TRCB)
- With auto discharge function when switch turned off
- ESD protected: Above 8kV (contact) IEC,4kV HBM, 1.5kV CDM
- Part No. and package

| Part No. | Package             | MSL     |  |
|----------|---------------------|---------|--|
| ET3159   | DFN4 (1.2mm ×1.6mm) | Level 1 |  |

## Application

- PDAs / smart phones
- Notebook / computers
- Portable media players
- Digital camera
- GPS navigation devices
- Data storage devices
- Optical, industrial, medical, and health-care devices

# **Pin Configuration**



## **Pin Function**

| Pin Number | Name | Function                             |  |
|------------|------|--------------------------------------|--|
| 1          | IN   | This is the input pin of the switch  |  |
| 2,5        | GND  | Ground connection                    |  |
| 3          | EN   | Enable input                         |  |
| 4          | OUT  | This is the output pin of the switch |  |

## **Block Diagram**



## **Functional Description**

The ET3159 is low-R<sub>ON</sub> P-channel load switches with controlled turn on and TRCB (True Reverse Current Blocking). The core of each device is a P-channel MOSFET and controller capable of functioning over a wide input operating range of 1.5 to 6.0V. The EN pin, an active HIGH GIOP input, controls the state of the switch. TRCB functionality blocks unwanted reverse current during ON and OFF when OUT higher than IN is applied.

#### Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into a discharged load capacitor or short-circuit, a capacitor must be placed between the IN and GND pins. At least  $1\mu$ F ceramic capacitor, C<sub>IN</sub>, placed close to the pins is usually sufficient. Higher-value C<sub>IN</sub> can be used to reduce the voltage drop in higher-current applications.

#### **Output Capacitor**

At least  $0.1\mu$ F capacitor, C<sub>OUT</sub>, should be placed between the OUT and GND pins. This capacitor prevents parasitic board inductance from forcing OUT below GND when the switch is on.

#### **Board Layout**

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effect that parasitic trace inductance may have on normal and short-circuit operation.

Using wide traces or large copper planes for all pins (IN, OUT, EN, and GND) helps minimize the parasitic electrical effects along with minimizing the case ambient thermal impedance.

## **Pulse Current Capability**

The device is mounted on the evaluation board shown in the PCB layout section. It is loaded with pulses of 6 A and 1 ms for periods of 4.6 ms.



The ET3159 can safely support 6A pulse current repetitively at 25 °C.

## Switch Non-Repetitive Pulsed Current

The ET3159 can withstand inrush current of up to 15A for 100µs at 25 °C when heavy capacitive loads are connected and the part is already enabled.

## **Absolute Maximum Ratings**

| F                           | Value   | Unit         |    |  |
|-----------------------------|---|--------------|----|--|
| Supply Ir                   | - 2 to 7  | V            |    |  |
| Enable Input Voltage (EN) , | - 2 to 7  | V            |    |  |
| Maximum Continu             | ous Switch Current (I <sub>MAX</sub> ) <sup>(3)</sup> | 3            |    |  |
| Maximum Repetitive Pulsed   | d Current (1 ms, 10 % Duty Cycle) <sup>(3)</sup>      | 6            | А  |  |
| Maximum Non-Repetitive Pu   | 15  |              |    |  |
|                             | Human Body Model, JESD22-A114                         | 4.0          | КV |  |
| ESD/Electrostatic           | Charged Device Model, JESD22-C101                     | 1.5          |    |  |
| Discharge Capability        | ESD Withstand Voltage IEC61000-4-2                    | 8.0(Contact) |    |  |
| Junction                    | - 40 to 150   | °C           |    |  |
| Thermal                     | 170   | °C/W         |    |  |
| Max Pow                     | 735   | mW           |    |  |

Notes:

- **1.** ET3159 can pass the 10V test (Instant Contact): can support up to 100mS 10V pulse.
- 2. Device mounted with all leads and power pad soldered or welded to PC board.
- **3**.  $T_A = 25 \ ^{\circ}C$ .

## **Recommended Operating Range**

| Parameter  | Value      | Unit |
|--|------------|------|
| Input Voltage Range (V <sub>IN</sub> )                 | 1.5 to 6.0 | V    |
| Operating Junction Temperature Range (T <sub>A</sub> ) | -40 to 85  | °C   |

## **Electrical Characteristics**

 $(V_{\text{IN}}=5V,\,T_{\text{A}}=-40^{\circ}\text{C}\text{ to }85^{\circ}\text{C}$  ,Typical values are at  $T_{\text{A}}=25^{\circ}\text{C}\text{)}$ 

| Symbol              | Parameter          | Test Conditions                      | Min | Тур | Max | Unit |
|---------------------|--------------------|--------------------------------------|-----|-----|-----|------|
| V <sub>IN</sub> (a) | Operating Voltage  |                                      | 1.5 |     | 6   | V    |
|                     |                    | $V_{IN} = 3.6 V, EN = active$        |     | 8   |     |      |
| la                  | Quiescent Current  | V <sub>IN</sub> = 4.3 V, EN = active |     | 10  |     |      |
|                     |                    | $V_{IN} = 5 V, EN = active$          |     | 11  | 14  | uA   |
| IQ_OFF              | Off Supply Current | EN = inactive, OUT = Open            |     |     | 1   |      |
|                     | Off Switch Current | EN = inactive, OUT = GND             |     |     | 1.2 |      |
|                     | On-Resistance      | $V_{IN} = 3.6 V, I_L = 100 mA,$      |     | 75  | 05  |      |
| Rds(on)             |                    | T <sub>A</sub> = 25 °C               | 75  |     | 95  | mΩ   |
|                     |                    | $V_{IN} = 4.3 V, I_L = 100 mA,$      | 70  |     | 90  |      |
|                     |                    | T <sub>A</sub> = 25 °C               |     |     |     |      |
|                     |                    | $V_{IN} = 5 V, I_L = 100 mA,$        | 65  |     | 85  |      |
|                     |                    | T <sub>A</sub> = 25 °C               |     |     |     |      |

# **Electrical Characteristics(Continued)**

| Symbol            | Parameter                                 | Test Conditions                            | Min | Тур | Мах | Unit  |
|-------------------|---|--|-----|-----|-----|-------|
| D                 | Output Pull Down                          | $V_{IN} = 5V, EN = 0V,$                    |     | 90  | 150 | Ω     |
| RPD               | Resistance                                | $V_{OUT}=1V, T_A = 25^{\circ}C$            |     |     |     |       |
| Ma                | EN Input Low                              | 1/10 - 15 1/106 V                          |     | 0.4 | 0.4 |       |
| VIL               | Voltage                                   | VIN = 1.5 V 100V                           |     |     | 0.4 | V     |
| M.                | EN Input High                             | $V_{\rm m} = 1.5 V_{\rm r}$ to 6V          | 15  |     |     | v     |
| V IH              | Voltage                                   | $VIN = 1.5 \ V \ 10 \ 0 V$                 | 1.5 |     |     |       |
| lonuz             | EN Input Leakage                          | $V_{EN} = 5 V, V_{IN} = 0 V$               |     |     | 10  |       |
| ISINK             |   | V <sub>EN</sub> =0 V, V <sub>IN</sub> =5 V | -1  |     |     | uA    |
| Pou po            | Pull-Down                                 |  | 0.6 | 1   | 1 / | MO    |
| NON_PD            | Resistance at EN pin                      |  | 0.0 | I   | 1.4 | IVIL2 |
|                   | RCB Protection                            |  |     | 15  |     | m\/   |
| V 1_RCB           | Trip Point <sup>(b)</sup>                 | VOUT - VIN                                 |     | 43  |     | 111V  |
|                   | RCB Protection                            |  |     | 25  |     | mV    |
| VR_RCB            | Release Trip Point <sup>(b)</sup>         | VIN - VOUT                                 |     |     |     |       |
|                   | RCB Hysteresis <sup>(b)</sup>             |  |     | 70  |     | mV    |
| 1                 | Vout Shutdown                             | Ven=0V, Vout=5V,                           |     |     | 2   | μA    |
| ISD_OUT           | Current                                   | V <sub>IN</sub> =Short to GND              |     |     |     |       |
| Trop ou           | RCB Response Time                         | V <sub>OUT</sub> - V <sub>IN</sub> =100mV  | 4.0 |     |     |       |
| I RCB_ON          | when Device EN <sup>(b)</sup>             | V <sub>EN</sub> =High                      |     | 4.0 |     | μs    |
| Trop.org          | RCB Response Time                         | V <sub>OUT</sub> - V <sub>IN</sub> =100mV  |     | 25  |     | 116   |
| I RCB_OFF         | Device OFF <sup>(b)</sup>                 | V <sub>EN</sub> =Low                       |     | 2.0 |     | μο    |
| <b>t</b> DON      | Turn-On Delay <sup>(c)</sup>              |  |     | 0.4 |     | ms    |
| t <sub>R</sub>    | V <sub>OUT</sub> Rise Time <sup>(c)</sup> | $V_{\rm IN} = 5V, R_{\rm L} = 15002,$      |     | 0.6 |     | ms    |
| ton               | Turn-On Time <sup>(d)</sup>               | $G_{L} = 100 \mu r, 1A = 25 G$             |     | 1.0 |     | ms    |
| t <sub>DOFF</sub> | Turn-Off Delay <sup>(c)</sup>             |  |     | 0.2 |     | ms    |
| t⊨                | V <sub>OUT</sub> Fall Time <sup>(e)</sup> | $V_{IN} = 5V, R_L = 150\Omega,$            |     | 9.4 |     | ms    |
| toff              | Turn-Off Time <sup>(e)</sup>              | $C_{L} = 100 \mu r, 1_{A} = 25^{\circ} C$  |     | 9.6 |     | ms    |

Notes:

a. If IN is float state, OUT is forbidden to connect power.

b. This parameter is guaranteed by design and characterization; not production tested.

c.  $t_{DON}/t_{DOFF}/t_R/t_F$  are defined in Figure 2.

d.  $t_{ON} = t_R + t_{DON}$ 

e.  $t_{OFF} = t_F + t_{DOFF}$ 

5

# Timing Diagram



## **Typical Characteristics**



Internally regulated,  $T_A = 25$  °C, unless otherwise noted

# **Application Circuits**



# Package Dimension

#### DFN4



# **Revision History and Checking Table**

| Version | Date      | Revision Item  | Modifier | Function & Spec<br>Checking | Package & Tape<br>Checking |
|---------|-----------|----------------|----------|-----------------------------|----------------------------|
| 1.7     | 2023-3-29 | Update Typeset | Shi Bo   | Liuxm                       | Zhu Jun Li                 |
|         |           |                |          |                             |                            |